

# MT81P02S

## P-Channel Enhancement Mode Field Effect Transistor

### Product Summary

- $V_{DS} = -30V$
- $I_D = -100A (V_{GS} = -10V)$
- $R_{DS(ON)} 6.0m\ \Omega @ V_{GS} = -10V$
- $R_{DS(ON)} 9.7m\ \Omega @ V_{GS} = -4.5V$

### Features

- Advanced Trench Process Technology.
- High Density Cell Design for Ultra Low On-Resistance.
- Lead free product is acquired.
- RoHS Compliant.

### Applications

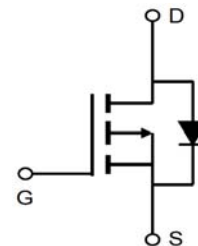
- Notebook Computer
- Portable Battery Pack



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### Simplified Schematic



### MARKING DIAGRAM & PIN ASSIGNMENT



### Absolute Maximum Ratings ( $T_A = 25^\circ C$ unless otherwise noted)

Symbol	Parameter	10s	Steady State	Units
$V_{DS}$	Drain-Source Voltage		-30	V
$V_{GS}$	Gate-Source Voltage		$\pm 20$	V
$I_D$	Continuous Drain Current		-100	A
$I_{DM}$	Pulsed Drain Current		-240	A
$I_S$	Continuous Source Current (Diode Conduction) <sup>1</sup>	-3.0	-1.58	A
$P_D$	Maximum Power Dissipation <sup>1</sup>		28	W
$T_J, T_{stg}$	Operating Junction and Storage Temperature Range		-55 to 150	$^\circ C$

### Thermal Resistance Ratings

Symbol	Parameter		Typical	Maximum	Unit
$R_{thJA}$	Maximum Junction-to-Ambient <sup>1</sup>	$t \leq 10$ Sec	36	46	$^\circ C/W$
		Steady State	65	80	
$R_{thJF}$	Maximum Junction-to-Foot (Drain)	Steady State	18	23	

Notes:

1. Surface Mounted on 1" x 1" FR4 Board.

**Electrical Characteristics** ( $T_A=25^\circ\text{C}$ , unless otherwise noted)

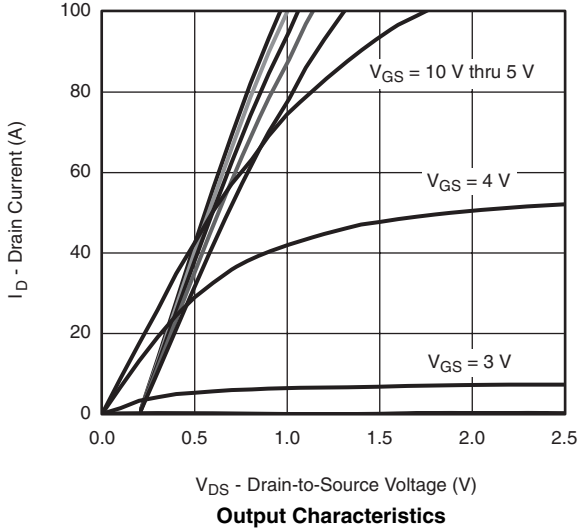
Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
<b>Static Characteristics</b>						
$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=-250\mu A$	-30	-	-	V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS}=V_{DS}, I_D=-250\mu A$	-1.0	-1.5	-2.5	V
$I_{GSS}$	Gate-Body Leakage Current	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	$\pm 100$	nA
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS}=-24V, V_{GS}=0V$	-	-	-1	$\mu A$
		$V_{DS}=-24V, V_{GS}=0V, T_J=70^\circ C$	-	-	-10	
$R_{DS(on)}$	Drain Source On State Resistance <sup>a</sup>	$V_{GS}=-10V, I_D=-13A$	-	6	7.8	m $\Omega$
		$V_{GS}=-4.5V, I_D=-10A$	-	9.7	13	
$g_{fs}$	Forward Transconductance <sup>a</sup>	$V_{DS}=-15V, I_D=-13A$	-	34	-	S
$V_{SD}$	Diode Forward Voltage <sup>a</sup>	$I_S=-2.7A, V_{GS}=0V$	-	-0.74	-1.2	V
<b>Dynamic Characteristics</b> <sup>b</sup>						
$C_{iss}$	Input Capacitance	$V_{DS}=-15V, V_{GS}=0V, \text{Frequency}=1\text{MHz}$	-	3240	-	pF
$C_{oss}$	Output Capacitance		-	380	-	
$C_{rSS}$	Reverse Transfer Capacitance		-	231	-	
$Q_g$	Total Gate Charge	$V_{DS}=-15V, V_{GS}=-10V, I_D=-20A$	-	61	-	nC
$Q_{gs}$	Gate-Source Charge		-	7.5	-	
$Q_{gd}$	Gate-Drain Charge		-	15.5	-	
$t_{d(on)}$	Turn-On Delay Time	$V_{DD}=-15V, R_L=1.5\Omega$ $I_D=-10A, V_{GEN}=-10V, R_G=1\Omega$	-	21	-	nSec
$t_r$	Rise Time		-	18	-	
$T_{d(off)}$	Turn-Off Delay Time		-	26	-	
$t_f$	Fall Time		-	8	-	
$R_g$	Gate Resistance	$V_{GS}=0, V_{DS}=0, f=1\text{MHz}$	-	2.4	-	$\Omega$
$t_{rr}$	Source-Drain Reverse Recovery Time	$I_F=-2.1A, di/dt=100A/\mu s$	-	15	-	nSec

Note:

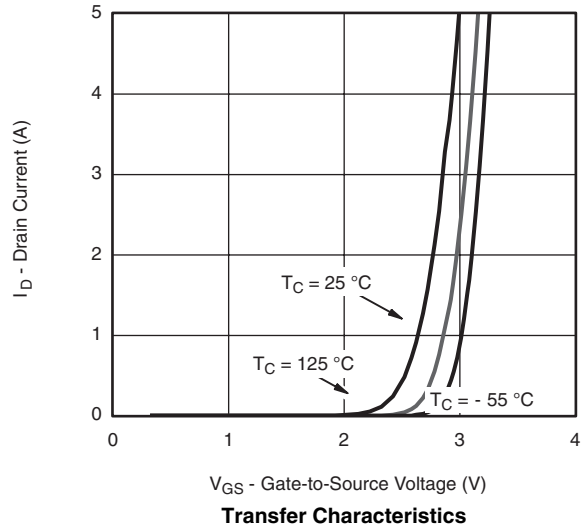
a. Pulse test; pulse width  $\leq 300\mu s$ , duty cycle  $\leq 2\%$ .

b. Guaranteed by design, not subject to production testing.

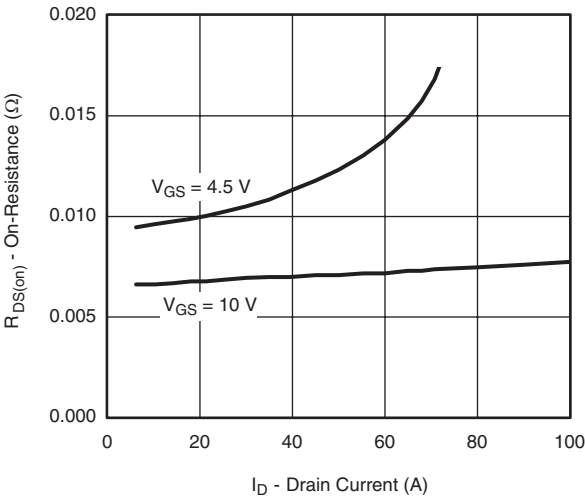
# Characteristics Curve



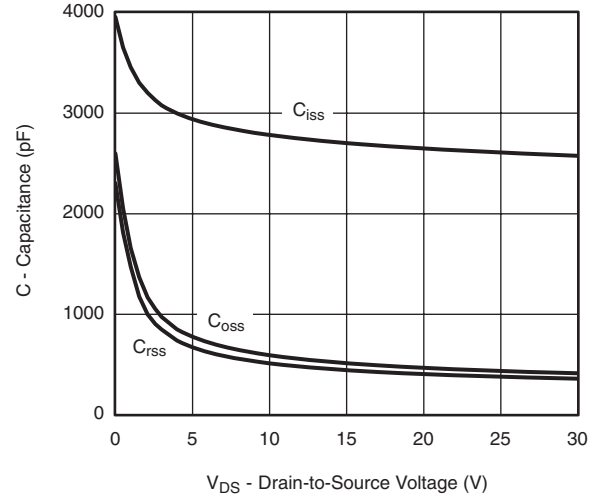
**Output Characteristics**



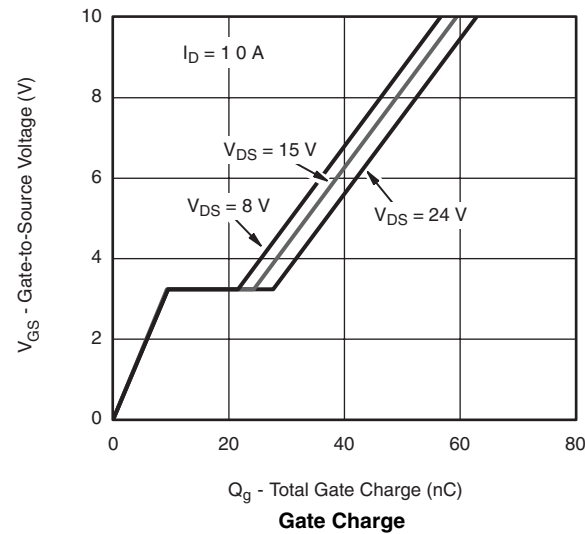
**Transfer Characteristics**



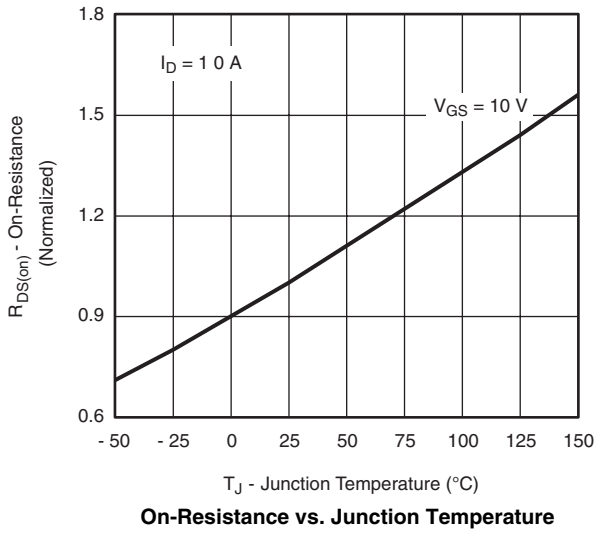
**On-Resistance vs. Drain Current**



**Capacitance**

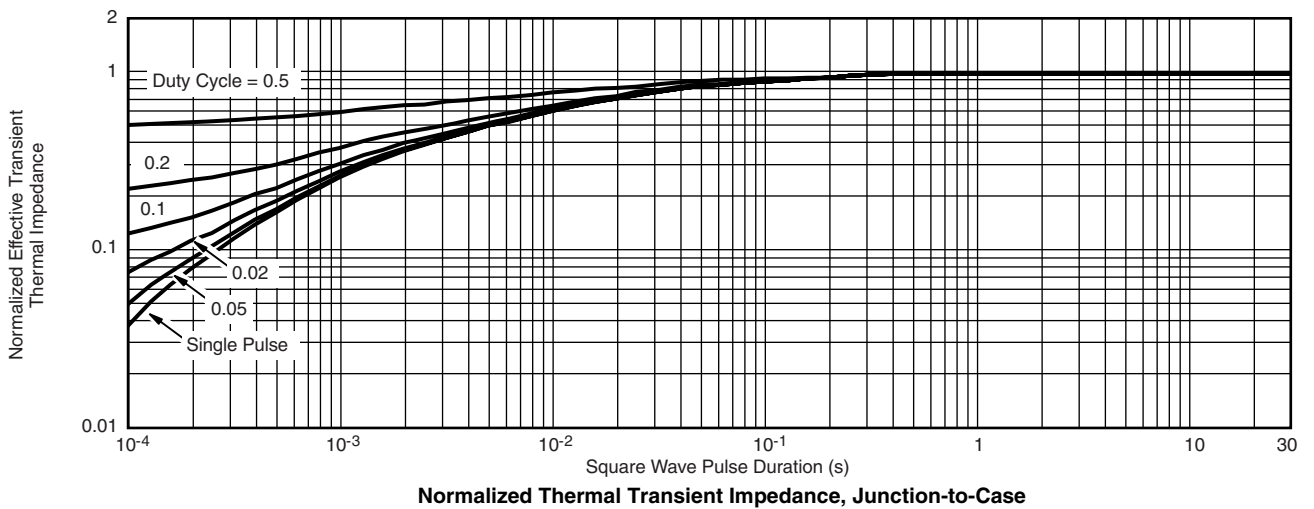
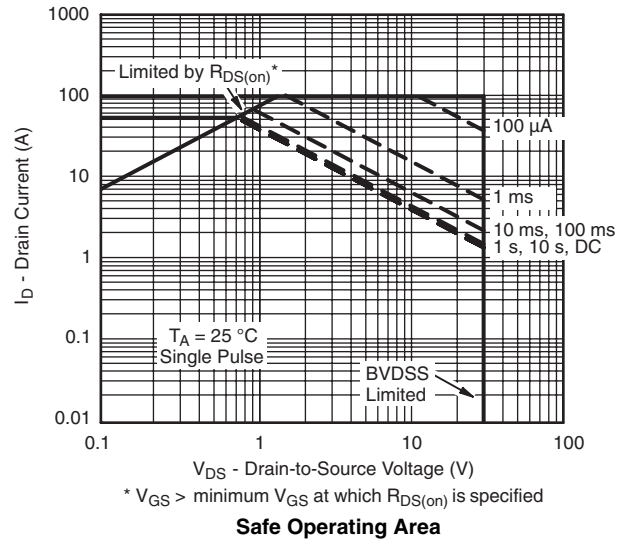
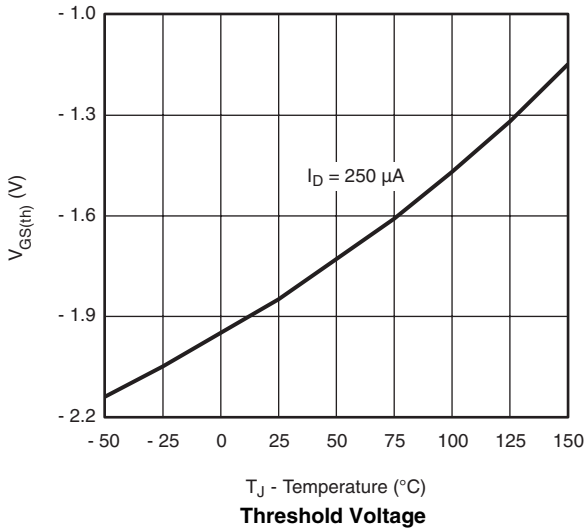
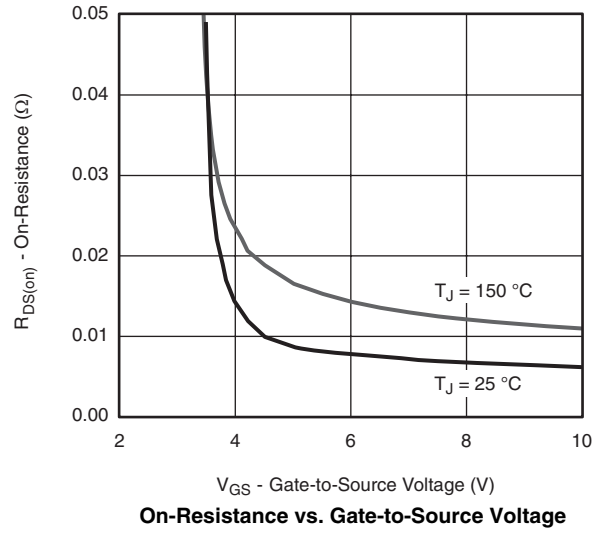
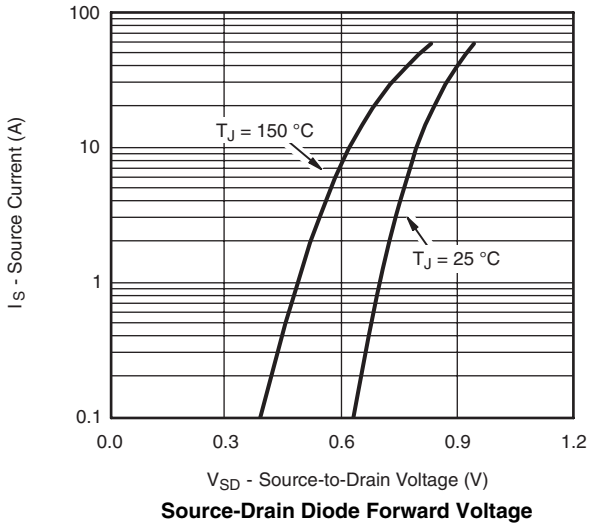


**Gate Charge**



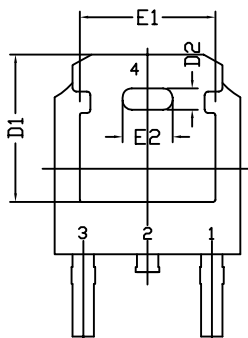
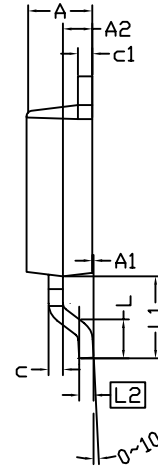
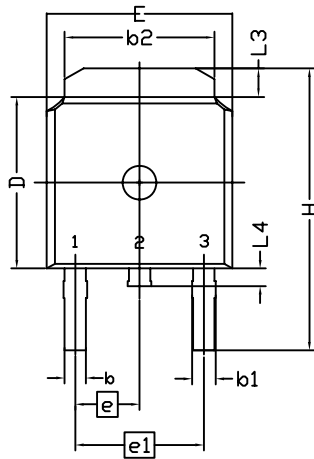
**On-Resistance vs. Junction Temperature**

# Characteristics Curve

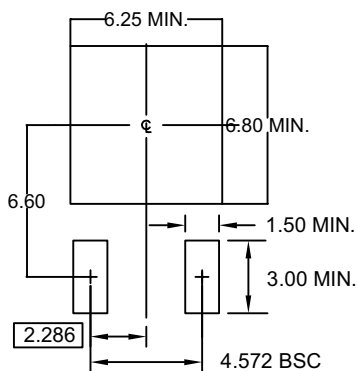


Document No.	PO-00009
Version	S

T0252(DPAK) PACKAGE OUTLINE



RECOMMENDED LAND PATTERN



UNIT: mm

NOTE

1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS. MOLD FLASH SHOULD BE LESS THAN 6 MILS.
2. DIMENSION L IS MEASURED IN GAUGE PLANE
3. TOLERANCE 0.10 mm UNLESS OTHERWISE SPECIFIED
4. CONTROLLING DIMENSION IS MILLIMETER. CONVERTED INCH DIMENSIONS ARE NOT NECESSARILY EXACT.
5. REFER TO JEDEC TO-252 (AA)

SYMBOL	DIMENSION IN MILLIMETERS			DIMENSIONS IN INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	2.184	2.286	2.388	0.086	0.090	0.094
A1	0.000	-----	0.127	0.000	-----	0.005
A2	0.889	1.041	1.143	0.035	0.041	0.045
b	0.635	0.762	0.889	0.025	0.030	0.035
b1	0.762	0.840	1.143	0.030	0.033	0.045
b2	4.953	5.340	5.461	0.195	0.210	0.215
c	0.450	0.508	0.610	0.018	0.020	0.024
c1	0.450	0.508	0.610	0.018	0.020	0.024
D	5.969	6.096	6.223	0.235	0.240	0.245
D1	5.210	5.249	5.380	0.205	0.207	0.212
D2	0.662	0.762	0.862	0.026	0.030	0.034
E	6.350	6.604	6.731	0.250	0.260	0.265
E1	4.318	4.826	4.901	0.170	0.190	0.193
E2	1.678	1.778	1.878	0.066	0.070	0.074
e	2.286 BSC			0.090 BSC		
e1	4.572 BSC			0.180 BSC		
H	9.398	10.033	10.414	0.370	0.395	0.410
L	1.270	1.520	2.032	0.050	0.060	0.080
L1	2.921 REF.			0.115REF.		
L2	0.408	0.508	0.608	0.016	0.020	0.024
L3	0.889	1.016	1.270	0.035	0.040	0.050
L4	0.635	-----	1.016	0.025	-----	0.040

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